Diode Semiconductor Device - Page 1 of 2



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| Inclosure Material: |
|---------------------|
| Metal |
| Overall Length: |

1.453 inches

Overall Diameter:

0.667 inches

Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-5

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.667 inches and 0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

720.0 nonrepetitive peak reverse voltage, peak total value and 600.0 reverse voltage, peak

Current Rating Per Characteristic:

35.00 amperes forward current, average absolute and 500.00 amperes forward current, average preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

Test Data Document:

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

Specification Data:

81349-mil-s-19500/297a government specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0



Mil-std (military Standard):

Mil-prf-19500 spec.